Synchronization of high-frequency oscillations of phase-slip centers in a tin whisker under m icrow ave radiation

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Current-voltage characteristics of a system with a variable number of phase-slip centers resulting from phase separation in a tin whisker under external microwave eld with a frequency =2 ' 35 45 GHz have been studied experimentally. Emergence and disappearance of steps with zero slope in a whisker's current-voltage characteristic at $U_{m=n} = (m=n)U$, where m and n are integers and U is determined by Josephson's form ula ~ = 2eU, have been investigated. Microwave eld generated by phase-slip centers is nonharm onic, and the system of phase-slip centers permits synchronization of internal oscillations at a microwave frequency by an external eld with a frequency which is the n-th harm onic of internal oscillations. The estimated microwave power generated by a

whisker is 10⁸ W. Stimulation of superconductivity in a current-carrying whisker has been detected.

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M icrow ave generation in a Josephson junction (a weakcoupling element in a superconducting circuit) under a dc voltage has attracted researchers' attention since the time when the ac Josephson e ect was discovered. The simple structure of the experimental device and easy control of the generated frequency are the most attractive features of the e ect. The frequency generated by the junction is determined by the form ula

! = 2U e=~;

where U is the voltage drop across the junction, e is the electron charge, and ~ is the P lanck constant. The disadvantages of these devices are their low output and di culties in m atching the superconducting circuits containing Josephson junctions to the m icrow ave circuits. A them pts have been m ade to overcom e these di culties using circuits of short junctions^{1,2,3,4}.

Josephson junctions have a typical linear size in the direction perpendicular to the supercurrent density vector, namely the Josephson penetration depth $_j$. If the junction dimension in the direction perpendicular to the supercurrent satis es the condition d < $_j$ (a short junction), the phase variation is uniform over the junction volume, and one has a single source of m icrow ave radiation. In the case of a network of short synchronized junctions, it seems possible to derive a high m icrow ave output close to the sum of powers generated by each element.

A long uniform superconducting channel with phaseslip centers can be classi ed with such system s. Phaseslip centers occur in resistive states of a long narrow channel carrying a constant current at a temperature close to the superconducting transition (I > I_c, T < T_c)^{5,6}. Real structures in which phase-slip centers have been detected are thin lm s with width w and single-crystal wires (whiskers) with diameter d smaller than the superconductor coherence length . From the viewpoint of experim enters dealing with superconducting channels, whiskers (thin crystalline wires) are preferable because their uniform ity over the length is higher. But thin Im s have some advantages when applications are concerned, since their dimensions are directly controlled during their manufacture. On the other hand, microscopic inhom ogeneities due to fabrication technologies can lead to considerable degradation of parameters of phase-slip centers, and a thin Im may behave like a system of weak superconducting bounds localized along the narrow Im.

An isolated phase-slip center is an nonstationary, inhom ogeneous entity "localized in the space" and containing an internal region with a size of about where the superconducting order parameter oscillates at the Josephson frequency

At tem peratures near the transition point, the voltage averaged over the oscillation period, U_{\perp} , in the phase-slip center is due to penetration of a non-uniform longitudinal electric eld into the outer region of the center through a distance of about l_{E} (the electric eld penetration range), and the electric resistance of each phase-slip center is

$$R_0 = 2_N l_E = S;$$

where $_{\rm N}$ is the material resistivity in the normal state and S is the channel cross section^{5,6,7,8}. At the moment when the absolute value of the order parameter vanishes, the phase di erence over the center jumps by 2 . Current-voltage characteristics (CVC) of such superconducting channels contain a set of sloped linear sections corresponding to resistances

$$R_n = nR_0$$
;

(where n is an integer) connected by sections of curves with current jumps. Extrapolations of these linear sections cross the current axis at approximately the same point I_0 (an excess current)^{5,6,7,9}.

A lthough the number of publications dedicated to phase-slip centers is fairly large^{5,6}, the dynamics of systems with phase-slip centers has been studied insu ciently^{7,8,10,11,12}. The reversed ac Josephson effect under external electrom agnetic radiation was detected in thin tim lm s at a frequency of 10 G H \vec{z} and in single-crystal wires (whiskers) at frequencies of up to 900 M H $z^{13,14,15}$. In both these cases, a CVC contains, in addition to sloping steps, a fundam ental step with a zero slope at voltage U in the region of param eters corresponding to one phase-slip center and associated with high-frequency oscillations of the order param eter in the center, and "weak" steps at

$$U_{m=n} = (m=n)U$$
;

where U is the voltage corresponding to the external eld frequency and m and n are integers. Ivlev and K opnin¹⁶ analyzed the ac Josephson e ect in terms of the m icroscopic theory. The pattern of various zero-slope steps at di erent direct currents and m icrow ave frequencies in systems with variable numbers of phase-slip centers has not been investigated in full. A current-carrying whisker under an electrom agnetic eld with a frequency higher than 900 M H z has never been studied.

II. SAM PLES AND EXPERIMENTAL DETAILS

In the reported work, we have studied the e ect of microw ave elds with frequencies ranging between 35 and 45 GHz on CVCs of tin whiskers in the regime when several phase-slip centers exist in a sample at voltages of order of U. In previous experiments^{7,13,14,15} the parameters T and =2 were selected so that the mean voltage U₁ across one center, which determined the frequency of proper high-frequency oscillations,

could be tuned to U $\,$, i.e., the frequency ! of internal oscillations should be equal to that of applied m icrowave

eld. W e have used higher m icrow ave frequencies =2 and tem peratures at a greater distance from T_c than T idecks et al.^{13,14,15} so that to satisfy the condition

$$U_1 = U = n$$

i.e., n! = (n > 1) when a sam ple contained several phase-slip centers at voltages about U . It follows from the microscopic theory¹⁶ that this is the condition under which induced steps on a CVC are generated at voltages U = n. The presence of such steps m eans that the radiation generated by the system of phase-slip centers is nonharm onic. Given the higher uniform ity of whiskers over their lengths and smaller number of structural defects than in Im s, they are preferable for such experiments. Moreover, zero-slope steps on a CVC of an irradiated whisker^{13,14,15} are considerably wider than in narrow

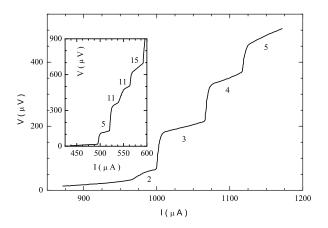


FIG.1: CVC of the Sn3 w hisker (R_0 0:19, T_c 3:71 K, $R_{300}=R_{4:2}$ 73) without irradiation by an external microwave eld at T 3:56 K. The insert shows the CVC of the Sn2 sample (R_0 0:21, T_c 3:72 K, d 0:8 m, $R_{300}=R_{4:2}$ 50) without irradiation at T 3:63 K.

 $\ln s^{7}$. In many experiments (see for example Ref.¹⁷), low-frequency oscillations instead of high-frequency oscillations were detected in narrow Im s. W hiskers grow n from thin tin Ims deposited on silicon substrates had diam eters d = 0.2 0.8 m, lengths of about 1 mm, resistance ratio $R_{300}=R_{4:2} < 100$, and T_c 3:1 K.A whisker was set across a 300-m gap in a thin tin lm about 1000 A thick. A whisker was attached to electrodes by electrostatic forces at the initial moment, then, apparently, by the Van der W aals forces. It is not easy to rem ove a whisker from the substrate surface. The heatsinking conditions, probably, were fairly good because the greater part of the sample was in contact with the polished substrate surface, therefore m easured CVCs did not exhibit a notable hysteresis in the studied tem perature range, unlike CVCs reported in Refs.^{13,14,15}. CVCs were measured using either the two-term inal con quration (this was possible because T_c of Im swashigher than that of whiskers) or the four-term inal con guration. The substrate supporting the whisker was placed in a copper waveguide and insulated from environment by a superconducting lead shield. The curves of the critical current and resistance versus tem perature for the case of a single T < 10 m K had shapes typical phase-slip center at T_C $T = T_{e}^{3=2}$, R₀ of whiskers¹³: I_c (1 (1 T = T)¹⁼⁴.

III. EXPERIMENTAL RESULTS

Current-voltage characteristics of all samples are piecewise linear, i.e., they are composed of linear sections connected by nonlinear sections with larger slopes. Figure 1 shows the examples of CVCs of superconducting whiskers with microwave radiation o . The initial parts of the whisker CVCs without microwaves are also show n

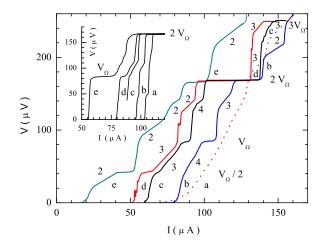


FIG.2: Set of CVCs of the Sn1 sample ($R_0 = 0.79 \quad 0.63$, $T_c \quad 3.69 \text{ K}$, d $\quad 0.3 \quad \text{m}$, $R_{300} = R_{4:2} \quad 20$) at dimensional microwave irradiation at frequency =2 = 40.62 GHz and T $\quad 3.62 \text{ K}$: (a) 70 dB (dashed line); (b) 36 dB; (c) 31 dB, (d) 30 dB, (e) 28.6 dB. The insert shows low-current sections of CVCs of the Sn1 sample at approximately equal parameters in another cycle of measurements: (a) 32.6 dB; (b) 30.6 dB; (c) 29 dB; (d) 28 dB; (e) 25.2 dB.

in Figs. 2-4 by dashed lines. The num bers near the linear sections of the whisker CVCs indicate the ratios between their resistances and that of a single phase-slip center, R_0 . The latter parameter was determined as the largest com m on divisor of di erential resistance values of all linear CVC sections and compared to an estimate derived from the size and resistivity of the whisker. The CVC linear sections are connected by nonlinear sections, which are reproducible and reversible in the range of studied frequencies. Note that in most experiments, the initial CVC sections at $I > I_c$ (curves (a) in Figs. 2 and 3) without radiation are nonlinear, and the st reproducible linear sections correspond to states with several phase-slip centers (the linear section $3R_0$ on curve (a) in Fig. 2 and $5R_0$ on curve (a) of Fig. 3). In earlier experiments^{13,14,15}, the states with one phase-slip center could be regularly produced. In contrast to those experiments, where the tem perature di erence T_c T was less than 10 mK, we m easured CVCsm ostly at tem peratures 70-160 mK below T_c. In this case, states with several phase-slip centers were stable at notably larger tem perature di erences T. This can be seen by comparing the CVC shown Tc in Fig. 1 with the CVC in the insert to this graph. M oreover, the linear sections with the same resistance (such as $3R_0$ sections on curve (a) in Fig. 2 for Sn1 and $2R_0$ in curve (d) in Fig. 4 for Sn3) separated by voltage jumps were recorded m any times. On the basis of these observations, we have come to the conclusion that, in spite of som e com plications in interpreting CVCs of our whiskers, they are superconducting channels with phase-slip centers at appropriate tem peratures and transport currents.

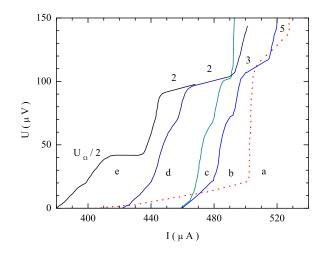


FIG.3: Set of CVCs of the Sn2 sample ($R_0 = 0.23$ 0:18 , T_c 3:72 K, d 0:8 m, R_{300} = $R_{4:2}$ 50) at dimensional event powers of m icrowaves at frequency =2 = 40:62 GHz at T 3:63 K: (a) 70 dB (dashed line); (b) 30.2 dB; (c) 30 dB; (d) 28.2 dB; (e) 26.1 dB.

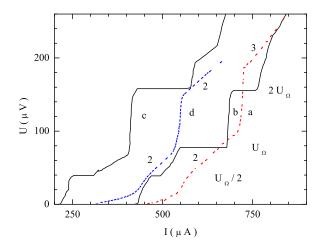


FIG.4: CVC of the Sn3 w hisker ($R_0 = 0.21$, T_c 3:71 K, $R_{300}=R_{4:2}$ 73) at di erent m icrow ave powers at frequency =2 = 37.5 G H z at T 3:58 K (curves a, b, and c) and T 3:63 K (curve d); (a) 70 dB (dashed line); (b) 19.5 dB; (c) 12 dB; (d) 70 dB (dashed line).

W hen samples are exposed to microwave radiation, their CVCs contain, in addition to linear sloping sections due to the presence of certain numbers of phase-slip centers, steps with a zero slope at voltages

$$U_{m=n} = (m = n)U$$
:

At low m icrowave powers, the channel critical current was higher, i.e., stimulation of superconductivity theoretically described by E liashberg¹⁸ took place. Instead of the emergence of the zero-slope step rst at U 13,14,15 , we observed the sequential appearance of steps at 2U , U, 3U, and U = 2 for a sample Sn1 (Fig. 2), and in Sn2 (Fig. 3) we rst observed a step at U = 2 and then at U (not shown in the graph). At lower tem peratures the unusual shapes of the CVCs at zero radiation intensity with linear sections of the same slope (curve (d) in Fig. 4) or the lowest linear sections corresponding to several phase-slip centers were replaced by more com mon CVC shapes. The sequence of m icrowave-induced steps in whiskers'CVCs emerging with increasing microwave power also became more like the usual sequence at lower tem peratures, namely, the step at U was detected rst, then the step at 2U , and at still higher m icrow ave power at U = 2 (Fig. 4). The curve became similar to those given in Refs.^{13,14,15}. As the m icrow ave power increased, the sloping linear sections due to the phase-slip centers becamemore pronounced on CVCs (Figs. 2 and 3).

Steps with zero slope emerge on linear sections of CVCs, which either exist in the samples not exposed to m icrowaves or appear in the samples irradiated by the m icrowave eld. For example, the step of zero slope on the CVC of the Sn1 whisker at U (insert to Fig. 2) appears after the em ergence of a linear section on the curve, its grow th, and the shift of its low er edge to the required voltage (curves (a), (b), and (c) in the insert to Fig. 2). As soon as the edge of the linear section achieves U, a zero-slope step is produced (curve (d), and its width increases with the microw ave power curve (e)). The steps at U =2 (curves (c), (d), and (e) in Fig. 2) emerge in a sim ilar manner. The step at 30 (curve (c) in Fig. 2) appears when the sloping linear section with di erential resistance 3R₀ extends to this region. A zero-slope step can disappear at a higherm icrow ave power (for exam ple, the steps at 3U , U , and U = 2) when the upper edge of the linear section shifts below the respective voltage, and a vertical CVC section moves to this region. In this case, the di erential resistance of the linear section can have a jump (curves (d) and (e) in Fig. 2), namely, the linear section at about 3U changed its factor from 3 to 2. Thus, a linear section on a CVC of a sample with or without m icrow ave pumping at $U_{m=n}$ is a necessary condition for form ation of a zero-slope step, i.e., for the existence of the required num ber of phase-slip centers in the sam ple.

By tuning the incident microwave frequency , we could detect zero-slope steps not observed previously when voltage $U_{\rm m\ =n}$ coincided with a linear section of a CVC recorded without irradiation.

Sloping linear sections in a CVC of a whisker containing a certain number of phase-slip centers and exposed to m icrowaves of a xed power could decrease their resistance factor with respect to the resistance of an isolated phase-slip center if the direct transport current increased (see curve (b) in Fig. 2). The resistance factor could also remain unchanged (curve (e) in Fig. 2, section 2). An increase in the incident m icrowave power could cause, in addition to suppression of both the critical and excess

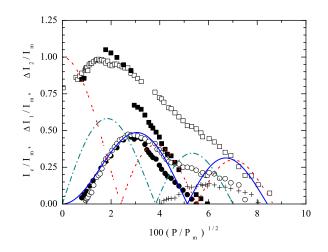


FIG.5: Normalized critical current $I_c = I_m$ versus the relative amplitude of external m icrowave eld at frequency =2 = 3:62 K for the Sn1 whisker in two di er-40:62 GHz at T ent cycles of m easurem ents (full squares are the data of the rst cycle and em pty squares correspond to the second cycle), 107 A.Norm alized widths of zero-slope steps on a CVC Im as functions of relative m icrowave eld am plitude at voltage (crosses plot data of the second cycle) and at voltage 2U U (full circles are the data of the st cycle and empty circles correspond to the second cycle). The dashed, dash-dotted, and solid lines show absolute values of Bessel functions $J_0(x)$, $J_1(x)$, and $J_2(x)$, respectively; $x = 100 (P = P_m)^{1=2}$, P is the power, and P_m is the maxim aloutput of the microwave generator.

current at a xed voltage, a switch-overto a linear section with a low erdi erential resistance. On the curves in Fig. 2, the resistance factor dropped from four to two, and in Fig. 3 from ve to two. The CVCs of the Sn2 whisker (Fig. 3) initially contained a linear section with resistance $5R_0$ at voltages above U , and under m icrow ave irradiation this parameter dropped to $3R_0$ and then $2R_0$. At higher m icrow ave powers the length of the $2R_0$ section increased at a constant resistance factor. Note that R_0 could vary under m icrow ave radiation within 20%. Thus, m icrow aves not only produce horizontal steps on CVCs, but also strongly a ect CVCs of tin whiskers.

We have also measured the widths of microwave induced steps as functions of the incident power over the interval of their existence. The experimental dependencies of current-normalized widths of zero-slope steps at voltages U and 2U, and of the critical current for a sample Sn1 obtained in di erent measurement cycles at approximately equal parameters as functions of the relative microwave amplitude are given in Fig. 5. The graph also shows as an illustration the absolute values of Bessel functions of order 0, 1, and 2 (J₀ (x), J₁ (x), and J₂ (x)) although we believe that the experimental curves are not directly related to these functions. Note the main features of the curves in Fig. 5. (1) The microwave stim ulation of superconductivity led to an increase in the critical current of about 20% . (2) The zero-slope step at 2U em erged at a low er m icrow ave pow er and had the m aximum width of about $0.5I_c$. (3) The step at U observed in the second cycle of measurements (it was too small in the rst cycle and its width is not shown in Fig. 5) appeared at a higher m icrow ave power, and in its presence the width of the 2U step and the critical current as functions of the microwave eld amplitude changed considerably. In this case the critical current and width of the 2U step vanished at a notably higher m icrow ave eld amplitude than in the st cycle. (4) Induced U and 2U steps appeared at a nite microw ave power, i.e., there is a certain threshold m icrowave power needed for form ation of these steps. This threshold is related to the extension of the linear CVC sections to voltages U and 2U . (5) There is only one interval of the microwave eld amplitude on which the critical current and CVC steps exist. No oscillations have been detected on the curves of critical current and step width.

In studying step widths as functions of the microwave power, we recorded (in several cases) nonmonotonic curves with relatively narrow down-peaks against the background of wide bell-shaped curves.

IV. DISCUSSION OF RESULTS

The current-voltage characteristic of a uniform superconducting channel, which is our model for a whisker, depends on its length. In the case of a short whisker section through which current is fed, 1 1, the presence of one phase-slip center allows the sample to conduct a current higher than the critical value. If l \mathbb{L} , the exponentially decaying parameters of phase-slip centers have little e ect on the channel properties, therefore it should contain several phase-slip centers, whose number is determined by the channel length. In our samples, the condition 1 l₂ was satis ed (l (10 2011), therefore we assume that several phase-slip centers were necessary to conduct a current slightly higher than the critical value. In the process of generation of the required num ber of centers, the instantaneous num ber of centers can be unstable and variable in both time and space.

The CVCs of our sam ples have piecew ise linear shapes with sections characterized by di erential resistance $R = nR_0$, where n is an integer. These sections correspond to de nite numbers of phase-slip centers, which can be derived from the sample sizes. In addition, there are the nonlinear sections on which the number of centers is probably unstable and varies with time. A dedicated investigation is needed to verify this hypothesis. The linear sections of CVCs of the superconducting channel in the sim pli ed model are described by the form ula

$$U = nR_0 (I = I_0)$$

The excess current I_0 is usually related to the average superconducting component of the total current. This

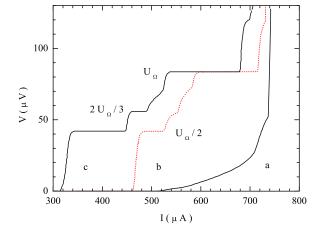


FIG.6: Low -current sections of CVCs of the Sn2 sample at di erent m icrow ave eld powers at frequency =2 = 40.62 GHz in the second cycle of measurements at T 3:60 K: (a) 70 dB; (b) 24.49 dB; (c) 22 dB.

form ula is not universal for all linear sections, because $I_0 \notin \text{const}$ for all groups of linear sections⁹. The CVCs of our samples contain neighboring linear sections with equal but di erent I_0 .

M icrow ave inradiation of our samples has a duale ect on their CVCs. The rst e ect is the generation of constant voltage steps, which was the main subject of the reported study. The second e ect is the change in the num ber of phase-slip centers under m icrow ave radiation and stabilization of CVC sections with de nite num bers of these centers. This shows up in the extension of linear sections and transform ation of som e nonlinear CVC portion to linear.

The existence of constant-voltage steps under microw ave radiation indicates that there are currents of microw ave frequencies with spectral components

in the regions of phase-slip centers. W hen the external frequency equals that of one of these harm onics, several centers are synchronized, which shows up in the form of constant-voltage steps at

$$U_m = m U_!$$
;

where m is the number of phase-slip centers,

and is the external radiation frequency. As a result, steps can occur at

if this voltage coincides with an inherent or m icrow aveinduced linear section of CVC with a de nite (integral) num ber of phase-slip centers. Unfortunately, it is di cult to determ inem and n with certainty using CVCs. Linear sections from which the number of centers could be exactly determ ined could be seen near constant-voltage steps only at certain values of parameters. We believe that the step at U =2 in Fig. 2 is due to the synchronization of two phase-slip centers by the fourth harm onic of proper oscillations, i.e., U =2 ! 2U =4, sim ilarly U ! 4U =4, 2U ! 4U =2, 3U ! 6U =2, the step at 4U ! 8U =2 is not shown; in Fig. 4 U =2 ! 2U =4, U ! 2U =4, U ! 4U =2; in Fig. 3, U =2 ! 2U =4; in Fig. 6, U =2 ! 3U =6, 2U =3 ! 4U =6, and U ! 6U =6. At other values of parameters this sam ple dem onstrated steps at 5U =6 ! 5U =6 and U =3 ! 2U =6 (not shown in the graphs of this paper).

Thus, at certain positions of these voltages in the whisker CVCs, microwave eld synchronizes oscillations of the order parameter in all phase-slip centers present in a sample, which results in constant voltage drops across isolated centers and across the entire sam ple. States with synchronized phase-slip centers under microwave radiation em erge predom inantly at corresponding locations in the CVCs. O ther CVC sections m ay correspond to states in which som e phase-slip centers are synchronized by external eld and the rest are not. This conjecture allows us to interpret the drop in the di erential resistance of linear sections (and the behavior of the di erential resistance in general) when the current increases under microw ave radiation. The existence of neighboring sloping steps with equal resistance but di erent excess current can also be interpreted in these terms. A similar e ect without microwave radiation can be attributed to a different but, in a sense, similar phenomenon. So-called Fiske steps¹⁹ were detected in experiments with tunneling Josephson junctions when the frequency generated by the junction was locked to the resonant frequency of the structural cavity in the experimental device. In this case, constant-voltage steps determined by the Josephson formula with the resonant cavity frequency could be seen on CVCs. The gap in the tin Im on which the whiskerwasmounted could act as a structural resonator. The length of this gap was about 5 mm, and, given the silicon substrate dielectric constant (" 12), we have a resonant frequency in the studied microwave band. In this case, a section with a constant voltage due to synchronization of a group of phase-slip centers (Fiske step) can occur. The centers whose oscillations are not locked to the resonant frequency should dem onstrate a linear behavior. As a result, the CVC of the sample should have a linear section with the resistance corresponding to the number of unlocked centers, which is smaller than the total number. The question why horizontal steps have not been observed remains unanswered. Doubts in this interpretation could be elim inated by directly measuring m icrow aves generated in the sam ple.

Figure 5 shows the widths of constant-voltage steps as functions of the microwave eld amplitude in relative units. The maximal width of these steps allows us to 6

P $(I)^2 m R_0;$

estim ate the m icrow ave power generated by the whisker:

where I is the step width in terms of current. Hence, P $\,$ 10 8 W .

Them icrow ave generation in the phase-slip centers can be interpreted in terms of the order parameter versus time, which vanishes at some moment and then increases to some value. At the moment when the order parameter is zero, the di erence between the phases on di erent sides of the phase-slip center drops by 2 . It would be interesting to estim ate the times of these processes and com pare their reciprocal values with the frequencies of the order parameter oscillations and external radiation. The most important parameter is the time in which the order parameter recovers. W hen is much longer than the order parameter oscillation period determined by the Josephson formula, both the mean and instantaneous absolute values of the order parameter within the center are much smaller than the equilibrium value in other regions of the superconducting channel. If com parable to or sm aller than the period of the order param eter oscillations, the instantaneous value of the gap in the phase-slip center can be large and comparable to the gap in the surrounding regions. The spectra of normal excitations in phase-slip centers should be notably di erent in these two cases, which can lead to di erences in som e electrical properties of phase-slip centers. Since the energy relaxation time of current carriers in tin is 10¹⁰ s, the rst case is realized in the microwave 3 frequency band.

The behavior of the step width is determined by two factors. The rst is the width of the step against the background of an in nite linear CVC section with a defin ite number of phase-slip centers as a function of the m icrowave eld am plitude. The second is the lim itation of the constant-voltage step by the length of the CVC linear sloping section, whose positions, as follows from experim ental data, are also functions of the m icrow ave power. A change in the number of phase-slip centers breaks the initial synchronization condition, and the system can switch to either a totally un-synchronized state, or a partially synchronized state, or fully synchronized state at a di erent harm onic and with a di erent num ber of phase-slip centers (for example, the zero-slope step at 2U in Fig. 2 can be due to synchronization of four centers by the second harm on ic or six centers by the third harm onic). Given these two e ects, we could not determ ine the constant-voltage step width as a function of the m icrowave amplitude unambiguously and compare it to the theoretical model. The existence of the microwave power threshold at which induced steps appear and the absence of oscillations in both the zero-slope step width $atU_{m=n}$ and critical current as functions of the m icrow ave

eld am plitude are due to a de nite num ber of phase-slip centers required at these voltages.

V. CONCLUSION

In the reported work, we have studied the e ect of m icrow ave radiation on current-voltage characteristics of whiskers with submicron diameters. Such whiskers can serve as m icrow ave oscillators at frequencies of up to 40 GHz with an output of about 10 8 W. The spectrum of generated waves contains m any harmonics, and the generation occurs on CVC sections with stable numbers

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of phase-slip centers. Features of CVCs of our sam ples under m icrow ave radiation are determ ined by changes in the num ber of phase-slip centers and the synchronization degree of generation in these centers.

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